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Ō	For receiving Office use only		
0-1	International Application No.		
0-2	International Filing Date		
0-3	Name of receiving Office and "PCT International Application"		
0-4	Form PCT/RO/101 PCT Request		
0-4-1	Prepared Using	PCT-SAFE [EASY mode] Version 3.50 (Build 0002.170)	
0-5	Petition The undersigned requests that the present international application be processed according to the Patent	,	
0-6	Cooperation Treaty Receiving Office (specified by the	Japan Patent Office (RO/JP)	
0-7	applicant) Applicant's or agent's file reference	03-00277WO	
1	Title of Invention	A SINGLE SILICON CRYSTAL, A SILICON WAFER, AN APPARATUS FOR PRODUCING THE SAME, AND A METHOD FOR PRODUCING THE SAME	
II	Applicant		
II-1	This person is	applicant only	
II-2	Applicant for	all designated States except US	
11-4	Name	Shin-Etsu Handotai Co., Ltd.	
II-5	Address	4-2 Marunouchi 1-chome, Chiyoda-ku, Tokyo 1000005 Japan	
II-6	State of nationality	JP	
11-7	State of residence	JP	
11-8	Telephone No.	03-3214-1831	
II-9	Facsimile No.	03-3215-9040	
II-11	Applicant's registration No. with the Office	000190149	

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111-1	Applicant and/or inventor		
111-1-1	This person is	applicant and inventor	
III-1-2	Applicant for	US only	
III-1-4	Name (LAST, First)	IIDA, Makoto	
III-1-5	Address	c/o Shirakawa R&D Center, Shin-Etsu Handotai Co., Ltd., 150, Aza Ohira, Oaza Odakura, Nishigo-mura, Nishishirakawa- gun, Fukushima 9618061 Japan	
III-1-6	State of nationality	JP	
111-1-7	State of residence	JР	
III-2	Applicant and/or inventor		
III-2-1	This person is	applicant and inventor	
111-2-2	Applicant for	US only	
111-2-4	Name (LAST, First)	IMAI, Toshihiko	
III-2-5	Address	c/o Shirakawa R&D Center, Shin-Etsu Handotai Co., Ltd., 150, Aza Ohira, Oaza Odakura, Nishigo-mura, Nishishirakawa- gun, Fukushima 9618061 Japan	
III-2-6	State of nationality	JP	
111-2-7	State of residence	JP	
III-3	Applicant and/or Inventor		
111-3-1	This person is	applicant and inventor	
III-3-2	Applicant for	US only	
111-3-4	Name (LAST, First)	SATO, Katsuichi	
III-3-5	Address	c/o Shirakawa R&D Center, Shin-Etsu Handotai Co., Ltd., 150, Aza Ohira, Oaza Odakura, Nishigo-mura, Nishishirakawa- gun, Fukushima 9618061 Japan	
	1		
III-3-6	State of nationality	JP	

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	T	T	
III-4	Applicant and/or inventor		
III-4-1	This person is	applicant and inventor	
111-4-2	Applicant for	US only	
111-4-4	Name (LAST, First)	IWABUCHI, Miho	
III-4-5	Address	c/o Shirakawa R&D Center, Shin-Etsu Handotai Co., Ltd., 150, Aza Ohira, Oaza Odakura, Nishigo-mura, Nishishirakawa- gun, Fukushima 9618061 Japan	
III-4-6	State of nationality	JP	
111-4-7	State of residence	JP	
III-5	Applicant and/or inventor		
III-5-1	This person is	applicant and inventor	
111-5-2	Applicant for	US only	
111-5-4	Name (LAST, First)	KATO, Masahiro	
III-5-5	Address	c/o Isobe R&D Center, Shin-Etsu Handotai Co., Ltd., 13-1, Isobe 2-chome, Annaka- shi, Gunma 3790196 Japan	
111-5-6	State of nationality	JP	
111-5-7	State of residence	JP	
IV-1	Agent or common representative; or address for correspondence The person identified below is hereby/ has been appointed to act on behalf of the applicant(s) before the competent International Authorities as:	agent	
IV-1-1	Name (LAST, First)	YOSHIMIYA, Mikio	
IV-1-2	Address	Uenosansei Bldg. 4F, 6-4, Motoasakusa 2-chome, Taito-ku, Tokyo 1110041 Japan	
IV-1-3	Telephone No.	03-3844-4501	
IV-1-4	Facsimile No.	03-3844-4505	
IV-1-5	e-mail	jdw07652@nifty.ne.jp	
IV-1-6	Agent's registration No.	100102532	

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v	DESIGNATIONS	<u> </u>	
V-1	The filing of this request constitutes under Rule 4.9(a), the designation of all Contracting States bound by the PCT on the international filing date, for the grant of every kind of protection available and, where applicable, for the grant of both regional and national patents.		
VI-1	Priority claim of earlier national application	,	
VI-1-1	Filing date	02 February 2004 (02	.02.2004)
VI-1-2	Number	2004-025923	
VI-1-3	Country	JР	
VI-2	Priority document request		
	The receiving Office is requested to prepare and transmit to the International Bureau a certified copy of the earlier application(s) identified above as item(s):	VI-1	
VII-1	International Searching Authority Chosen	Japan Patent Office	(ISA/JP)
VIII	Declarations	Number of declarations	
VIII-1	Declaration as to the identity of the inventor	-	
VIII-2	Declaration as to the applicant's entitlement, as at the international filing date, to apply for and be granted a patent	-	
VIII-3	Declaration as to the applicant's entitlement, as at the international filing date, to claim the priority of the earlier application	-	
VIII-4	Declaration of inventorship (only for the purposes of the designation of the United States of America)	-	
VIII-5	Declaration as to non-prejudicial disclosures or exceptions to lack of novelty	-	
IX	Check list	number of sheets	electronic file(s) attached
IX-1	Request (including declaration sheets)	5	✓
IX-2	Description	22	-
IX-3	Claims	4	-
IX-4	Abstract	1	✓
IX-5	Drawings	2	-
IX-7	TOTAL	34	

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	Accompanying Items	paper document(s) attached	electronic file(s) attached
IX-8	Fee calculation sheet	√	•
IX-17	PCT-SAFE physical media	-	✓
IX-19	accompany the abstract	4	
IX-20	Language of filing of the international application	Japanese	
X-1	Signature of applicant, agent or common representative		
X-1-1	Name (LAST, First)		
X-1-2	Name of signatory		
X-1-3	Capacity		

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10-1	Date of actual receipt of the purported international application	
10-2	Drawings:	
10-2-1	Received	
10-2-2	Not received	
10-3	Corrected date of actual receipt due to later but timely received papers or drawings completing the purported international application	
10-4	Date of timely receipt of the required corrections under PCT Article 11(2)	
10-5	International Searching Authority	ISA/JP
10-6	Transmittal of search copy delayed until search fee is paid	

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11-1	Date of receipt of the record copy by	
	the International Bureau	